NSN 5962-01-293-1167

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-293-1167 **Body Length:** 1.490 inches **Body Width:** 0.600 inches **Body Height:** 0.205 inches **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and ultraviolet erasable and programmed and electrostatic sensitive and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 15 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 22.0 volts power source **Time Rating Per Chacteristic:** 250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

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Yes - demil/mli